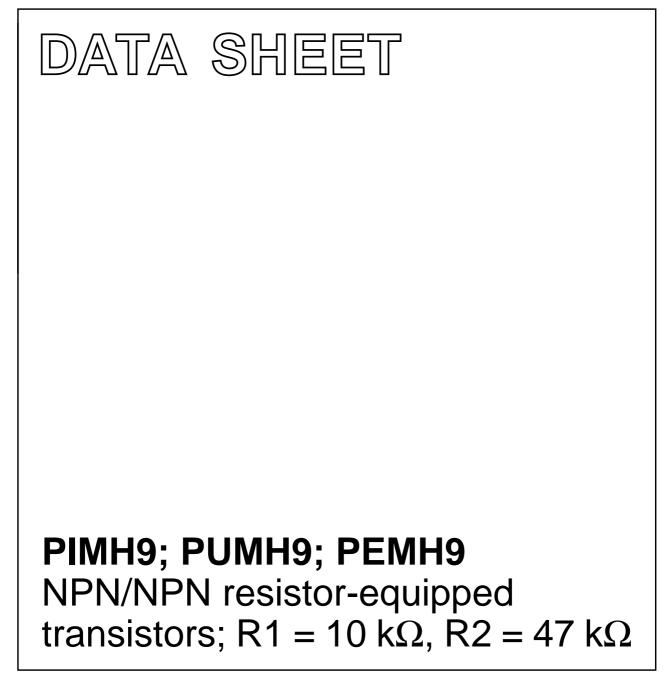
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 2003 Sep 15 2004 Apr 14



PIMH9; PUMH9; PEMH9

FEATURES

- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- · Reduces pick and place costs.

APPLICATIONS

- General purpose switching and amplification
- Inverter and interface circuits
- Circuit driver.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V _{CEO}	collector-emitter voltage	-	50	V
l _o	output current (DC)	-	100	mA
TR1	NPN	-	-	-
TR2	NPN	—	_	_
R1	bias resistor	10	_	kΩ
R2	bias resistor	47	_	kΩ

DESCRIPTION

NPN/NPN resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

PRODUCT OVERVIEW

TYPE NUMBER	PACKA	AGE	MARKING CODE	PNP/PNP	NPN/PNP COMPLEMENT	
	PHILIPS	EIAJ	MARKING CODE	COMPLEMENT		
PEMH9	SOT666	_	H9	PEMB9	PEMD9	
PIMH9	SOT457	SC-74	H9	-	-	
PUMH9	SOT363	SC-88	H*9 ⁽¹⁾	PUMB9	PUMD9	

Note

1. * = p: Made in Hong Kong.

* = t: Made in Malaysia.

* = W: Made in China.

SIMPLIFIED OUTLINE, SYMBOL AND PINNING

TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL		PINNING		
	SIMPLIFIED OUTLINE AND STMBOL	PIN	DESCRIPTION		
PEMH9		1	emitter TR1		
PIMH9	6 5 4	2	base TR1		
PUMH9		3	collector TR2		
		4	emitter TR2		
		5	base TR2		
		6	collectorTR1		
	Top view MHC049				

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ORDERING INFORMATION

		PACKAGE	
TYPE NUMBER NAME		DESCRIPTION	VERSION
PEMH9	 plastic surface mounted package; 6 leads 		SOT666
PIMH9	 plastic surface mounted package; 6 leads 		SOT457
PUMH9	 plastic surface mounted package; 6 leads 		SOT363

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT		
Per transistor							
V _{CBO}	collector-base voltage	open emitter	_	50	V		
V _{CEO}	collector-emitter voltage	open base	_	50	V		
V _{EBO}	emitter-base voltage	open collector	_	10	V		
Vi	input voltage positive negative		-	+40	V		
lo	output current			100	mA		
I _{CM}	peak collector current		_	100	mA		
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$					
	SOT363	note 1	-	200	mW		
	SOT457	note 1	-	300	mW		
	SOT666	notes 1 and 2	-	200	mW		
T _{stg}	storage temperature		-65	+150	°C		
Tj	junction temperature		_	150	°C		
T _{amb}	operating ambient temperature		-65	+150	°C		
Per device	·		·				
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C					
	SOT363	note 1	-	300	mW		
	SOT457	note 1	_	600	mW		
	SOT666	notes 1 and 2	_	300	mW		

Notes

1. Device mounted on an FR4 printed-circuit board, single-sided copper, standard footprint.

2. Reflow soldering is the only recommended soldering method.

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
Per transist	tor	•	•	
R _{th(j-a)}	thermal resistance from junction to ambient	T _{amb} ≤ 25 °C		
	SOT363	note 1	625	K/W
	SOT457	note 1	417	K/W
	SOT666	notes 1 and 2	625	K/W
Per device		•	•	
R _{th(j-a)}	thermal resistance from junction to ambient	T _{amb} ≤ 25 °C		
	SOT363	note 1	416	K/W
	SOT457	note 1	208	K/W
	SOT666	notes 1 and 2	416	K/W

Notes

1. Device mounted on an FR4 printed-circuit board, single-sided copper, standard footprint.

2. Reflow soldering is the only recommended soldering method.

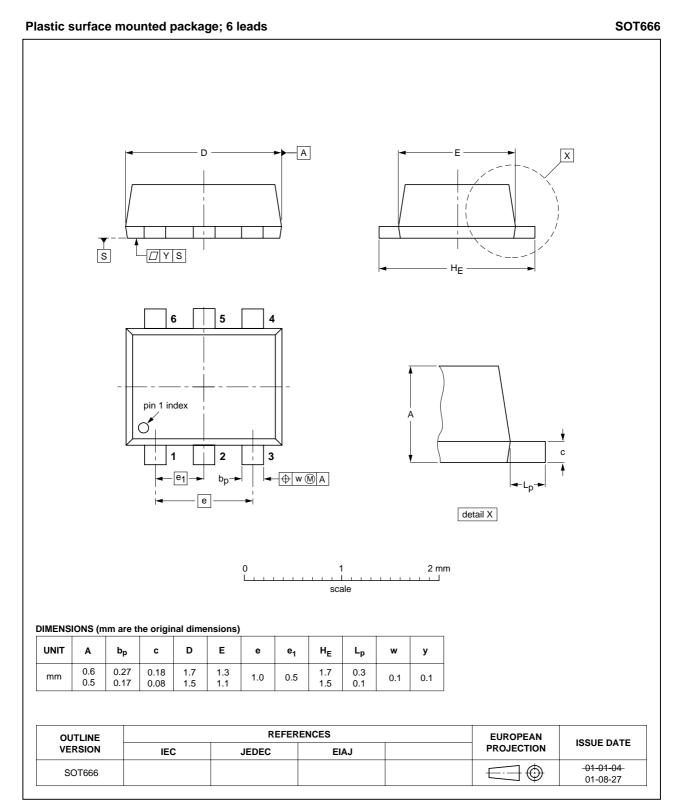
CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

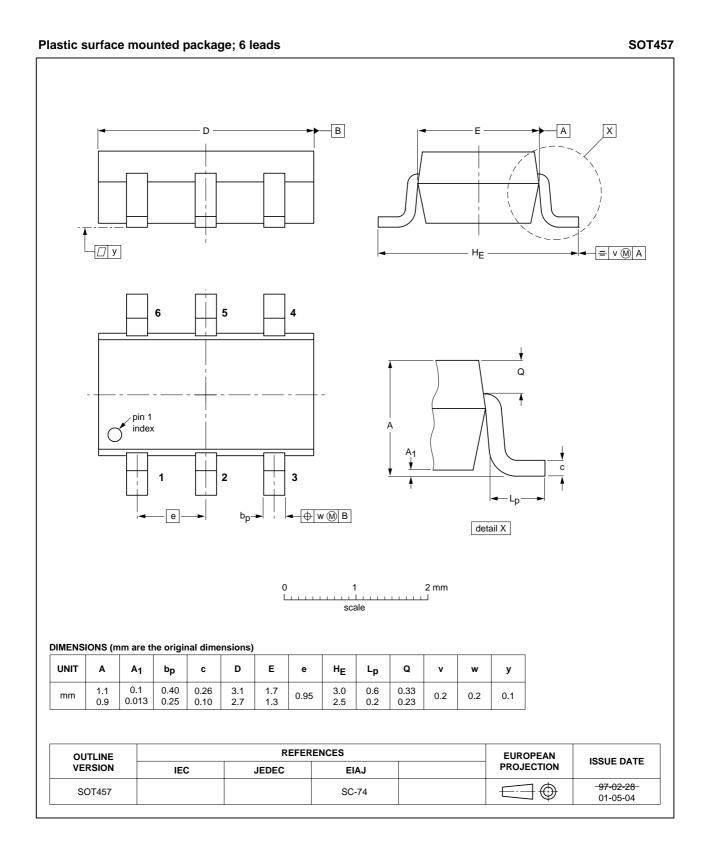
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	V _{CB} = 50 V; I _E = 0 A	-	-	100	nA
I _{CEO}	collector-emitter cut-off current	V _{CE} = 30 V; I _B = 0 A	-	-	1	μA
		$V_{CE} = 30 \text{ V}; \text{ I}_{B} = 0 \text{ A}; \text{ T}_{j} = 150 ^{\circ}\text{C}$	-	-	50	μA
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A	-	-	150	μA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 5 \text{ mA}$	100	-	_	
V _{CEsat}	collector-emitter saturation voltage	$I_{\rm C} = 5 \text{ mA}; I_{\rm B} = 0.25 \text{ mA}$	-	-	100	mV
V _{i(off)}	input-off voltage	$V_{CE} = 5 \text{ V}; \text{ I}_{C} = 100 \mu\text{A}$	-	0.7	0.5	V
V _{i(on)}	input-on voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 1 \text{ mA}$	1.4	0.8	_	V
R1	input resistor		7	10	13	kΩ
R2 R1	resistor ratio		3.7	4.7	5.7	
C _c	collector capacitance	$\label{eq:VCB} \begin{array}{l} V_{CB} = 10 \text{ V}; \text{ I}_{E} = \text{i}_{e} = 0 \text{ A}; \\ \text{f} = 1 \text{ MHz} \end{array}$	-	-	2.5	pF

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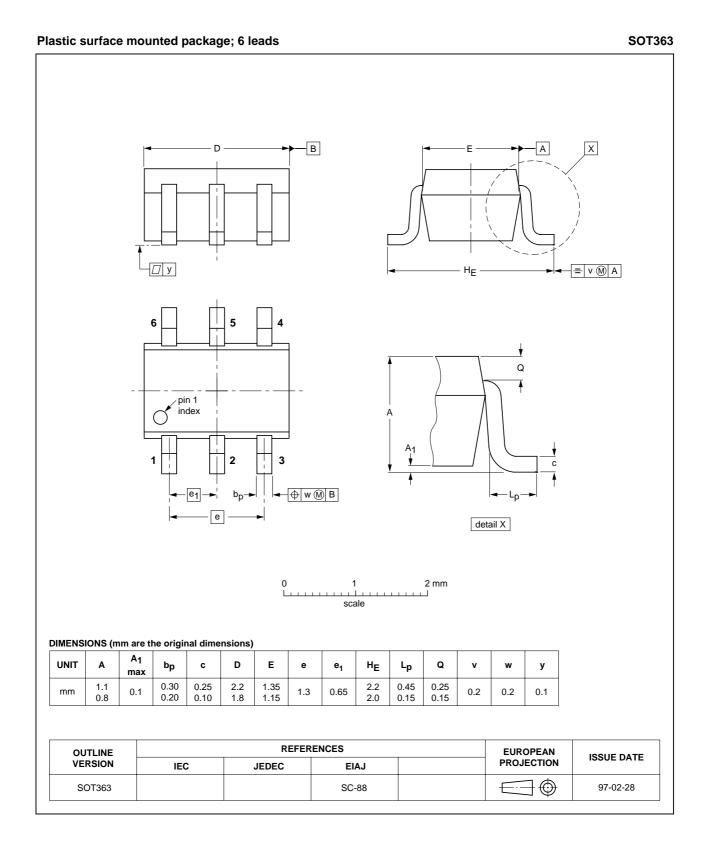
PACKAGE OUTLINES



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DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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